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APPLICANTS

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** CONTINUING DATA *****
 This application is a DIV of 10/320,660 12/17/2002 PAT 6,700,167
 which is a DIV of 09/759,639 01/16/2001 PAT 6,528,854 *WLL*

** FOREIGN APPLICATIONS *****
 JAPAN 2000-010250 01/17/2000 *WLL*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
 ** 04/26/2004

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 (a-d) conditions <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance Examiner's Signature <i>WLL</i> Initials	STATE OR COUNTRY JAPAN	SHEETS DRAWING 23	TOTAL CLAIMS 20	INDEPENDENT CLAIMS 3
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ADDRESS
 20987
 VOLENTINE FRANCO, & WHITT PLLC
 ONE FREEDOM SQUARE
 11951 FREEDOM DRIVE SUITE 1260
 RESTON, VA
 20190

TITLE
 METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE INCLUDING A MOSFET WITH NITRIDE
 SIDEWALLS

<input type="checkbox"/> All Fees
<input type="checkbox"/> 1.16 Fees (Filing)